

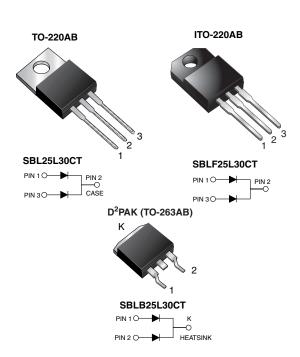
SBL25L30CT, SBLF25L30CT, SBLB25L30CT

Vishay General Semiconductor

HALOGEN

FREE

Dual Low V_F Common Cathode Schottky Rectifier



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 12.5 A				
V_{RRM}	30 V				
I _{FSM}	180 A				
V _F	0.39 V				
T _J max.	150 °C				
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB)				
Circuit configuration	Common cathode				

FEATURES

- Power pack
- Low power loss, high efficiency
- · Very low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for D²PAK (TO-263AB) package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available
 Automotive ordering code:
 Base P/NHE3 (for ITO-220AB)
 Base P/NHM3 (for D²PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency inverters, switching mode power supplies, freewheeling diodes, OR-ing diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Base P/NHE3_X - RoHS-compliant, AEC-Q101 qualified

("_X" denotes revision code, e.g. A, B, ...)

Base P/N-M3 - RoHS-compliant, halogen-free, commercial grade

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum



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MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	SBL25L30CT SBLB25L30CT SBLF25L30CT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	30	V	
Maximum average forward rectified current at T _C = 95 °C	total device	I _{F(AV)}	25		
	per diode		12.5	Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	180	, ,	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +150	°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink, t = 1 min		V_{AC}	1500	V	

ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUE	UNIT	
Maximum instantaneous forward valtage	V _F ⁽¹⁾	12.5 A	T _J = 125 °C	0.39	V	
Maximum instantaneous forward voltage			T _J = 25 °C	0.49		
Maximum instantaneous reverse current at DC blocking voltage per diode	I _R ⁽²⁾	Rated V _R	T _J = 25 °C	0.90		
			T _J = 100 °C	50	mA	
			T _J = 125 °C	100		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	SBL25L30CT	SBLF25L30CT	SBLB25L30CT	UNIT
Typical thermal resistance from junction to case per diode	$R_{ heta JC}$	1.5	4.0	1.5	°C/W

ORDERING INFORMATION						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	SBL25L30CT-E3/45	1.85	45	50/tube	Tube	
ITO-220AB	SBLF25L30CT-E3/45	1.99	45	50/tube	Tube	
D ² PAK (TO-263AB)	SBLB25L30CT-M3/I	1.35	I	800/reel	Tape and reel	
ITO-220AB	SBLF25L30CTHE3_A/P (1)	1.99	Р	50/tube	Tube	
D ² PAK (TO-263AB)	SBLB25L30CTHM3/I (1)	1.35	I	800/reel	Tape and reel	

Note

 $^{(1)}$ AEC-Q101 qualified, available in ITO-220AB and D2PAK (TO-263AB)

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RATINGS AND CHARACTERISTICS CURVES (T_C = 25 °C unless otherwise noted)

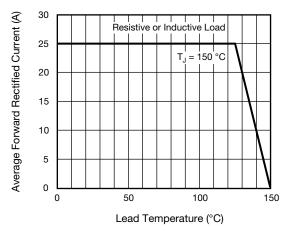


Fig. 1 - Forward Current Derating Curve

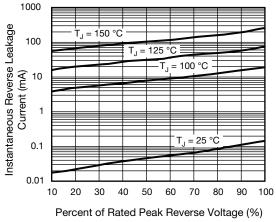


Fig. 4 - Typical Reverse Characteristics Per Diode

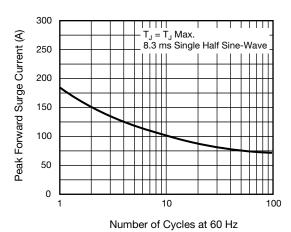


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

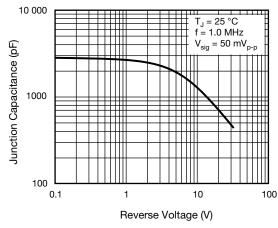


Fig. 5 - Typical Junction Capacitance Per Diode

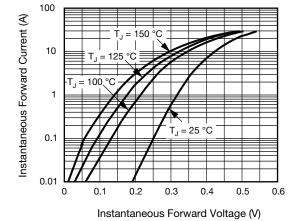


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

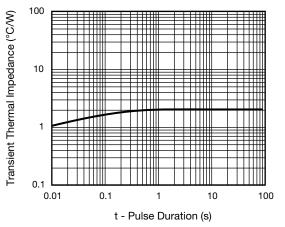


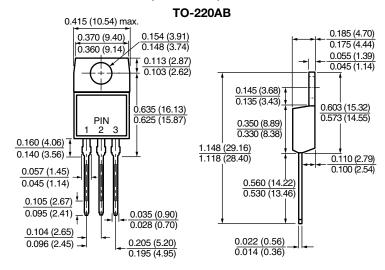
Fig. 6 - Typical Transient Thermal Impedance Per Diode

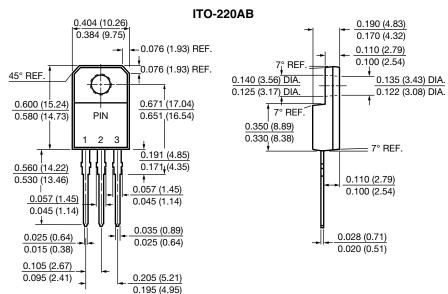




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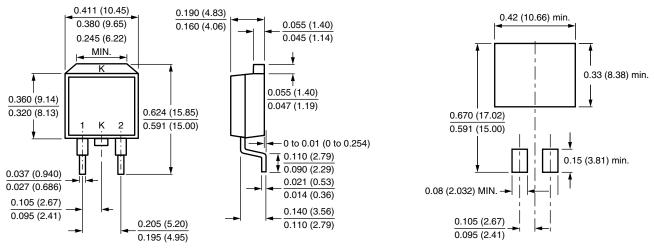
PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





D²PAK (TO-263AB)

Mounting Pad Layout





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